



**THE DATASHEET OF
DCX144EH-7**



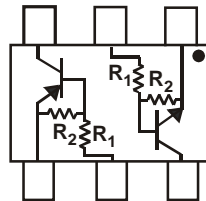
**COMPLEMENTARY NPN/PNP PRE-BIASED
SMALL SIGNAL TRANSISTORS in SOT563**
Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

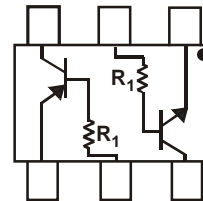
Part Number	R1	R2	Marking
DCX124EH	22k Ω	22k Ω	C17
DCX144EH	47k Ω	47k Ω	C20
DCX143EH	4.7k Ω	4.7k Ω	C08
DCX114YH	10k Ω	47k Ω	C14
DCX123JH	2.2k Ω	47k Ω	C06
DCX114EH	10k Ω	10k Ω	C13
DCX143TH	4.7k Ω	—	C07
DCX114TH	10k Ω	—	C12

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 $\text{\textcircled{E3}}$
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)



R₁, R₂ Device Schematic
Top View

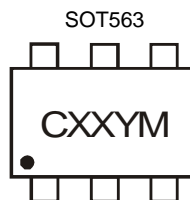


R₁ Only Device Schematic
Top View

Ordering Information (Note 4)

Part Number	Packaging	Shipping
DCX124EH-7	SOT563	3,000/Tape & Reel
DCX144EH-7	SOT563	3,000/Tape & Reel
DCX143EH-7	SOT563	3,000/Tape & Reel
DCX114YH-7	SOT563	3,000/Tape & Reel
DCX123JH-7	SOT563	3,000/Tape & Reel
DCX114EH-7	SOT563	3,000/Tape & Reel
DCX143TH-7	SOT563	3,000/Tape & Reel
DCX114TH-7	SOT563	3,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information


CXX = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: F = 2018
 M = Month ex: 9 = September

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024
Code	F	G	H	I	J	K	L

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings NPN Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		V_{CC}	50	V
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	V_{IN}	-10 to +40 -10 to +40 -10 to +30 -6 to +40 -5 to +12 -10 to +40 -5V Max -5V Max	V
Output Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	I_O	30 30 100 70 100 50 100 100	mA
Output Current	All	I_C (Max)	100	mA
Power Dissipation	(Total)	P_D	150	mW
Thermal Resistance, Junction to Ambient Air	(Note 5)	$R_{\theta JA}$	833	$^\circ\text{C/W}$
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Note: 5. Mounted on FR-4 Board with recommended pad layout at <http://www.diodes.com/package-outlines.html>.

Maximum Ratings PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage		V_{CC}	-50	V
Input Voltage	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	V_{IN}	+10 to -40 +10 to -40 +10 to -30 +6 to -40 +5 to -12 +10 to -40 +5V max +5V max	V
Output Current	DCX124EH DCX144EH DCX143EH DCX114YH DCX123JH DCX114EH DCX143TH DCX114TH	I_O	-30 -30 -100 -70 -100 -50 -100 -100	mA
Output Current	All	I_C (Max)	-100	mA
Power Dissipation	(Total)	P_D	150	mW
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic (DCX143TH & DCX114TH Only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _E = 50μA
Collector Cut-Off Current	I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cut-Off Current	I _{EBO}	—	—	0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TH I _C /I _B = 1mA / 0.1mA DCX114TH
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 6)	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DCX124EH	0.5	1.1	—	V	V _{CC} = 5V, I _O = 100μA
	DCX144EH	0.5	1.1	—		
	DCX143EH	0.5	1.1	—		
	DCX114YH	0.3	—	—		
	DCX123JH	0.5	—	—		
	DCX114EH	0.5	1.1	—		
Input Voltage	DCX124EH	—	1.9	3.0	V	V _O = 0.3V, I _O = 5mA V _O = 0.3V, I _O = 2mA V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 1mA V _O = 0.3V, I _O = 5mA V _O = 0.3V, I _O = 10mA
	DCX144EH	—	1.9	3.0		
	DCX143EH	—	1.9	3.0		
	DCX114YH	—	—	1.4		
	DCX123JH	—	—	1.1		
	DCX114EH	—	1.9	3.0		
Output Voltage	DCX124EH	—	0.1	0.3	V	I _O /I _I = 10mA / 0.5mA I _O /I _I = 10mA / 0.5mA I _O /I _I = 10mA / 0.5mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 5mA / 0.25mA I _O /I _I = 10mA / 0.5mA
	DCX144EH	—	0.1	0.3		
	DCX143EH	—	0.1	0.3		
	DCX114YH	—	—	—		
	DCX123JH	—	—	—		
	DCX114EH	—	0.1	0.3		
Input Current	DCX124EH	—	—	0.36	mA	V _I = 5V
	DCX144EH	—	—	0.18		
	DCX143EH	—	—	1.8		
	DCX114YH	—	—	0.88		
	DCX123JH	—	—	3.6		
	DCX114EH	—	—	0.88		
Output Current	I _{O(OFF)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EH	56	—	—	—	V _O = 5V, I _O = 5mA V _O = 5V, I _O = 5mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 10mA V _O = 5V, I _O = 5mA
	DCX144EH	68	—	—		
	DCX143EH	20	—	—		
	DCX114YH	68	—	—		
	DCX123JH	80	—	—		
	DCX114EH	30	—	—		

Note: 6. Transistor - For Reference Only.

Electrical Characteristics PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic (DCX143TH & DCX114TH Only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	—	V	I _E = -50μA
Collector Cut-Off Current	I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cut-Off Current	I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	-0.3	V	I _C /I _B = -2.5mA / -0.25mA DCX143TH I _C /I _B = -1mA / -0.1mA DCX114TH
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = -1mA, V _{CE} = -5V
Gain-Bandwidth Product (Note 6)	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V _{I(OFF)}	-0.5	-1.1	—	V	V _{CC} = -5V, I _O = -100μA
		-0.5	-1.1	—		
-0.5		-1.1	—			
-0.3		—	—			
-0.5		—	—			
-0.5		-1.1	—			
Input Voltage	V _{I(ON)}	—	-1.9	-3.0	V	V _O = -0.3V, I _O = -5mA V _O = -0.3V, I _O = -2mA V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -1mA V _O = -0.3V, I _O = -5mA V _O = -0.3V, I _O = -10mA
		—	-1.9	-3.0		
		—	-1.9	-3.0		
		—	-1.4	-3.0		
		—	-1.1	-3.0		
		—	-1.9	-3.0		
Output Voltage	V _{O(ON)}	—	-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -10mA / -0.5mA
		—	-0.1	-0.3		
		—	-0.1	-0.3		
		—	-0.1	-0.3		
		—	-0.1	-0.3		
		—	-0.1	-0.3		
Input Current	I _I	—	—	-0.36	mA	V _I = -5V
		—	—	-0.18		
		—	—	-1.8		
		—	—	-0.88		
		—	—	-3.6		
		—	—	-0.88		
Output Current	I _{O(OFF)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	G _I	56	—	—	—	V _O = -5V, I _O = -5mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA
		68	—	—		
		20	—	—		
		68	—	—		
		80	—	—		
		30	—	—		
Gain-Bandwidth Product (Note 6)	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor - For Reference Only.

Typical Curves – DCX143EH NPN Section

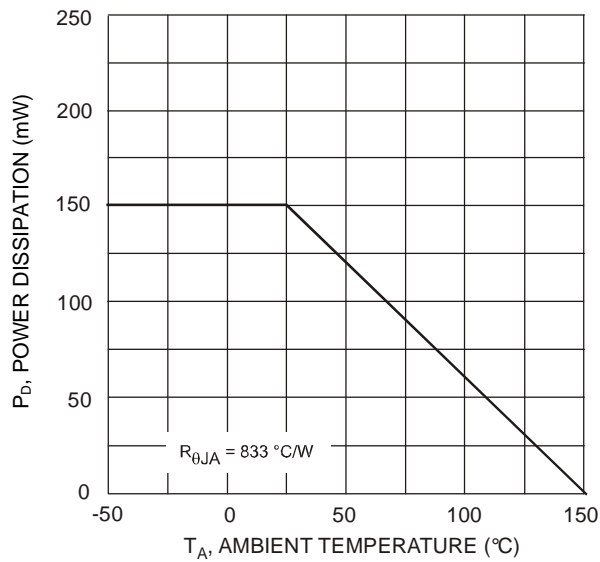


Fig. 1 Derating Curve - Total

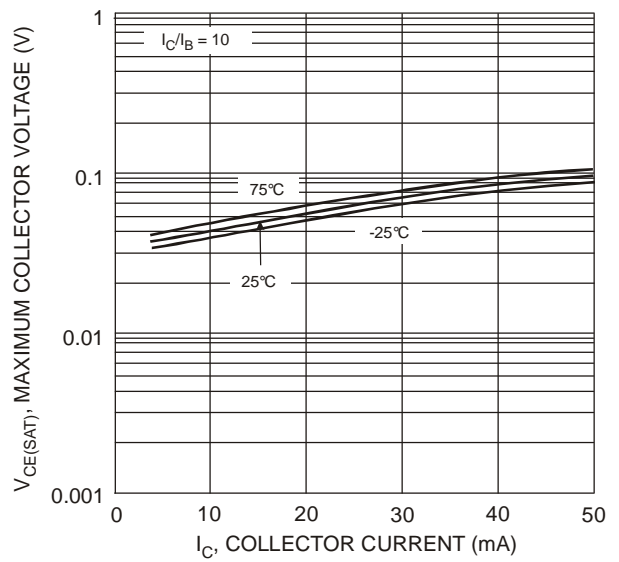


Fig. 2 $V_{CE(SAT)}$ vs. I_C

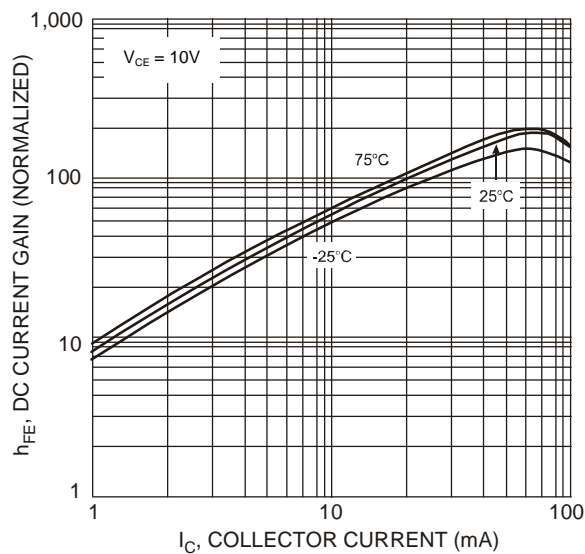


Fig. 3 DC Current Gain

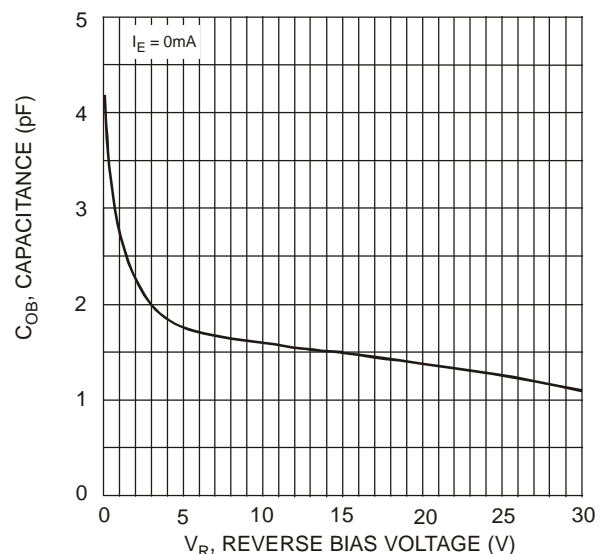


Fig. 4 Output Capacitance

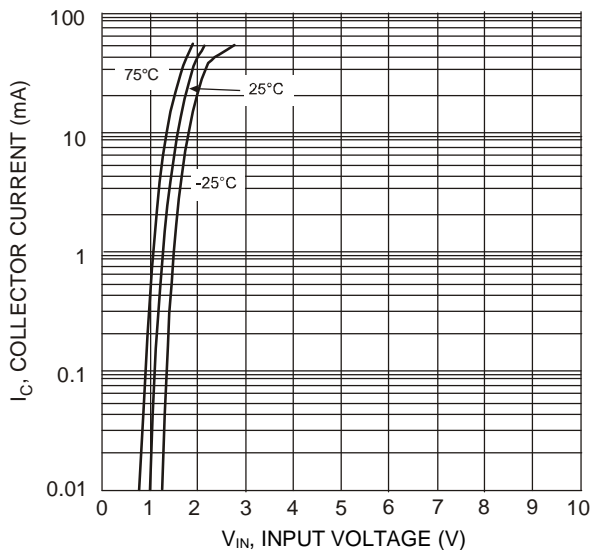


Fig. 5 Collector Current vs. Input Voltage

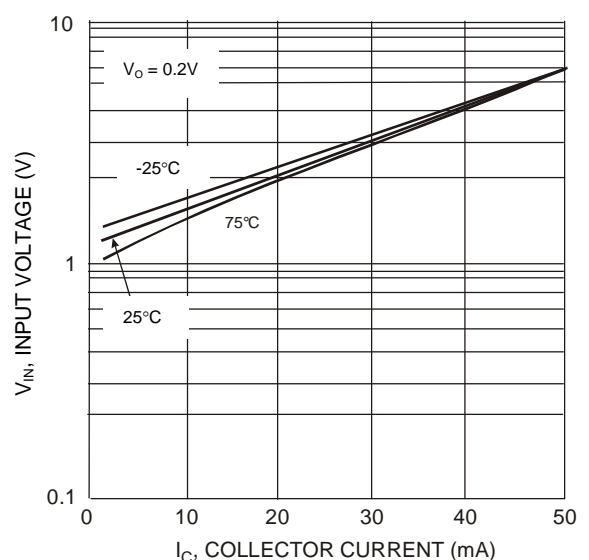


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DCX143EH PNP Section

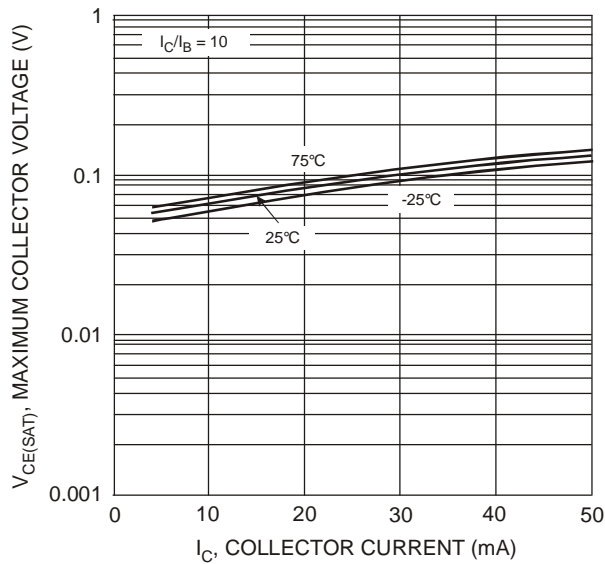


Fig. 7 $V_{CE(SAT)}$ vs. I_C

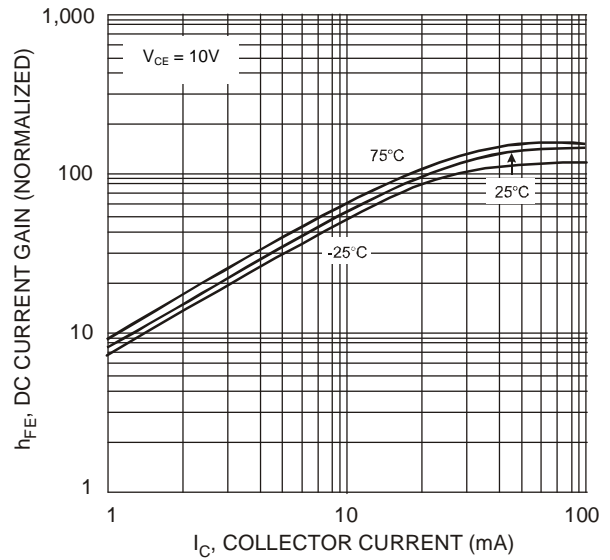


Fig. 8 DC Current Gain

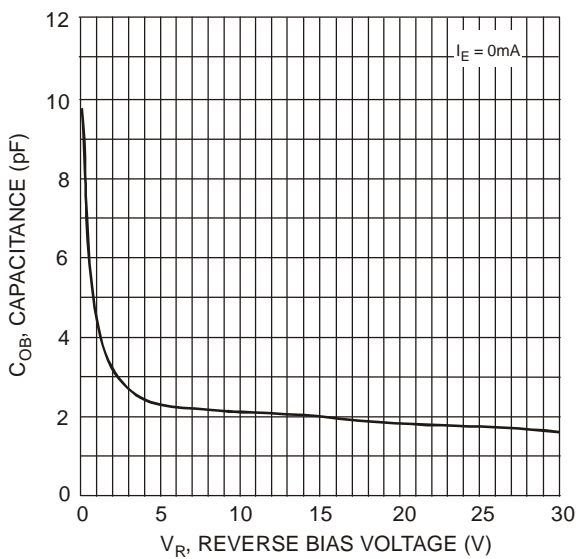


Fig. 9 Output Capacitance

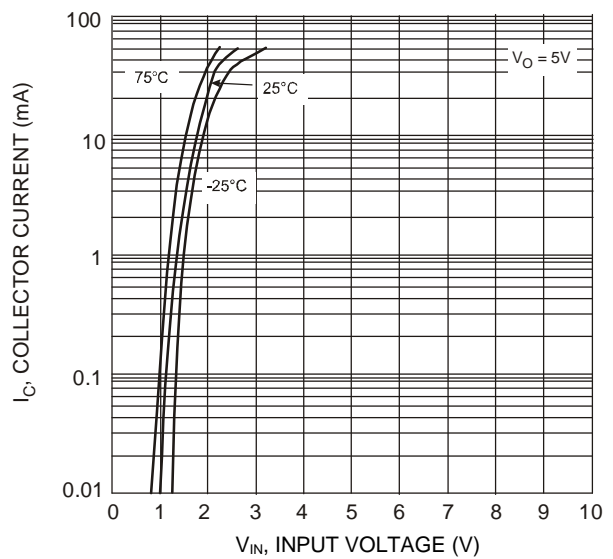


Fig. 10 Collector Current vs. Input Voltage

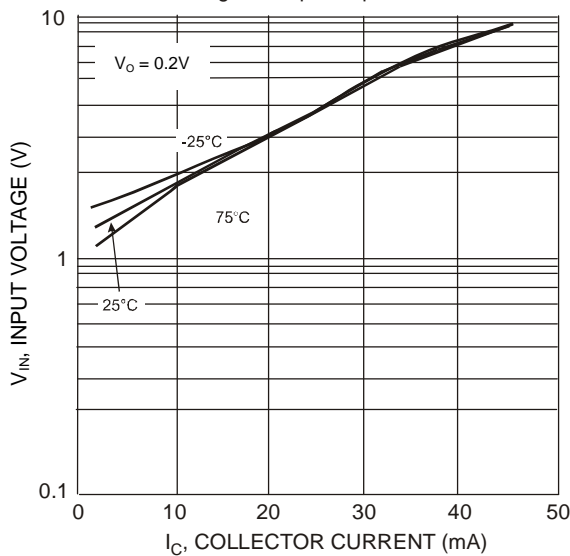
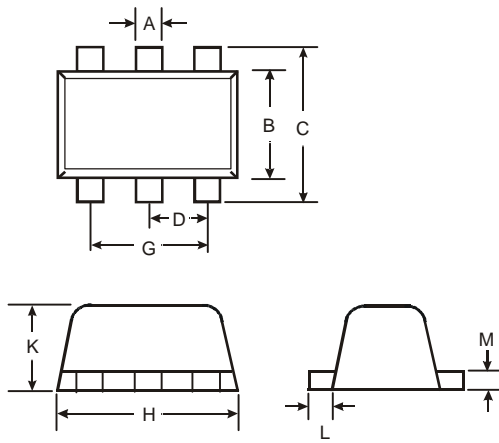


Fig. 11 Input Voltage vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT563

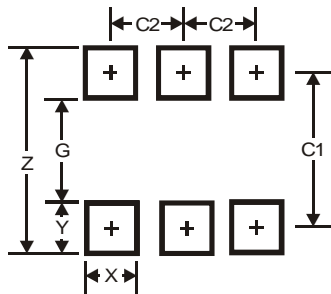


SOT563			
Dim	Min	Max	Typ
A	0.15	0.30	0.20
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	-	-	0.50
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.55	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT563



Dimensions	SOT563
Z	2.2
G	1.2
X	0.375
Y	0.5
C1	1.7
C2	0.5

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